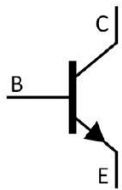


VRW056 M M QSQ æ M ç s ll 1 Silicon NPN transistor in a SOT

High voltage, high current, high h_{FE} linearity.

Audio frequency general purpose amplifier applications.

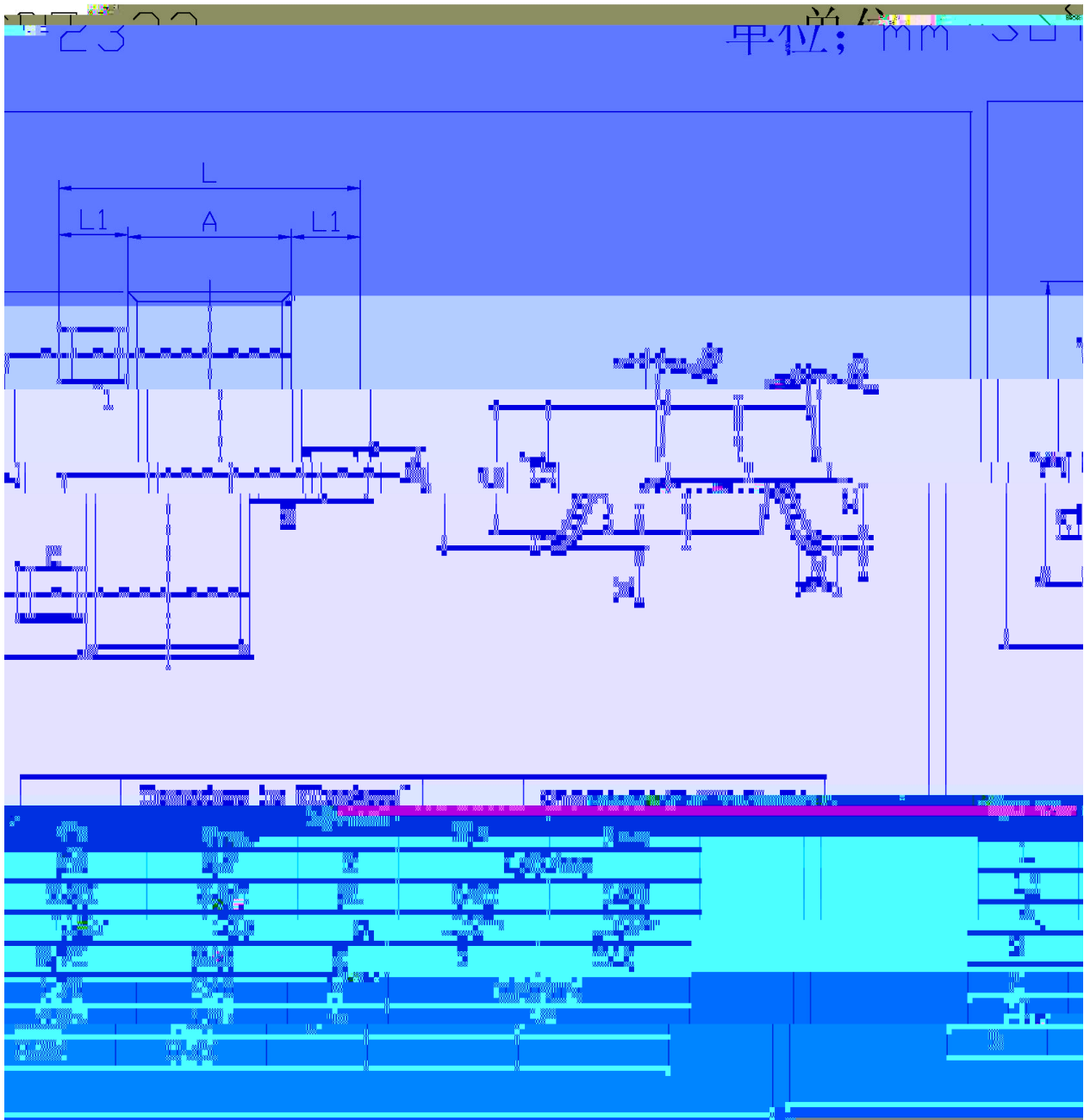


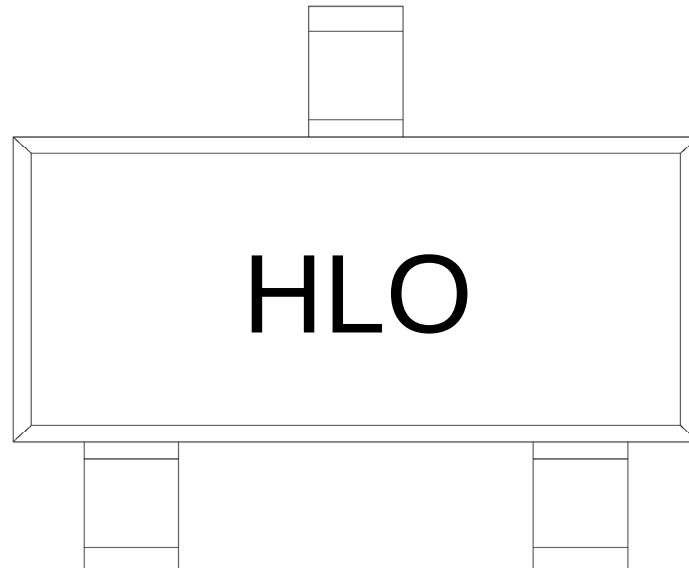
PIN1 χ Base PIN 2 χ Emitter PIN 3 χ Collector

h_{FE} Classifications		O					
Symbol							
h_{FE} Range	70	140	120	240	200	400	350 700
Marking	H01 GLL						

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V _{CBO}	60	V







" X

K X 标识符

0 X 标识符

R X h_{FE}^6 标识符

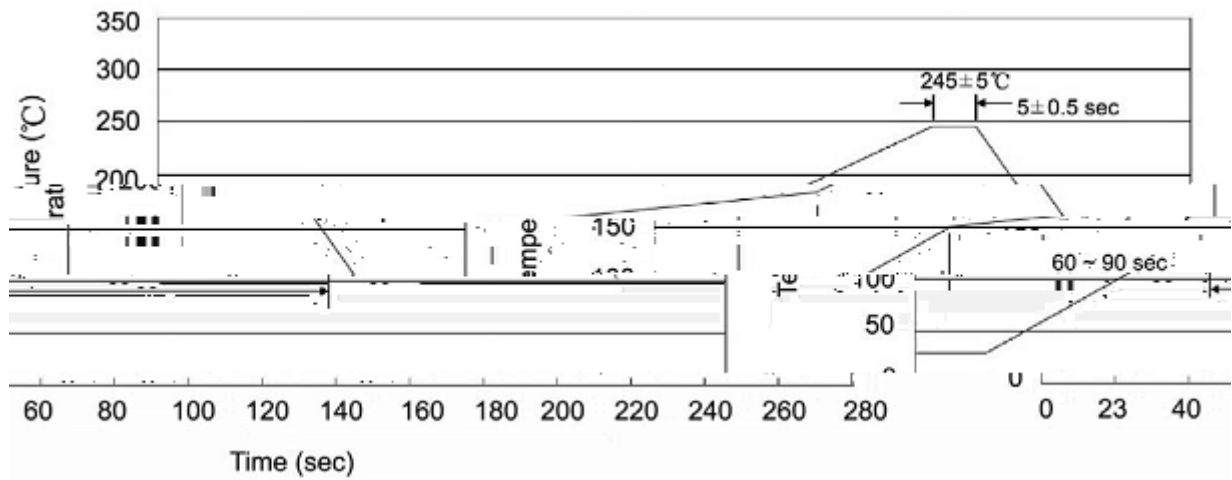
Note:

K X Company Code

0 X Product Type Code

R X h_{FE} Classifications Symbol

Temperature Profile for IR Reflow Soldering(Pb-Free)



1. Preheating: 25~150 °C, Time: 60~90sec;
2. Peak Temp.: 245±5 °C, Duration: 5±0.5sec;
3. Cooling Speed: 2~10 °C/sec.

- Note:
1. Preheating: 25~150 °C, Time: 60~90sec.
2. Peak Temp.: 245±5 °C, Duration: 5±0.5sec.
3. Cooling Speed: 2~10 °C/sec.

□ 260±5 °C, Time: 10±1 sec. Temp.: 260±5 Time: 10±1 sec

□ / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱
						ρ		